

2SC4805G

Silicon NPN epitaxial planar type

For 2 GHz band low-noise amplification

■ Features

- High transition frequency f_T
- S-Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing and the magazine packing

■ Absolute Maximum Ratings $T_a = 25^{\circ}C$

Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V_{CBO}	15	V	
Collector-emitter voltage (Base open)	V _{CEO}	10	V	
Emitter-base voltage (Collector open)	V _{EBO}	2	V	
Collector current	I_{C}	65	mA	
Collector power dissipation	P_{C}	150	mW	
Junction temperature	T _j	150	°C	
Storage temperature	T_{stg}	-55 to +150	°C	

Package

- Code
 - SMini3-F2
- Marking Symbol: 3S
- Pin Name
 - 1: Base
 - 2: Emitter
- 3: Collector

■ Electrical Characteristics $T_a = 25$ °C ± 3 °C

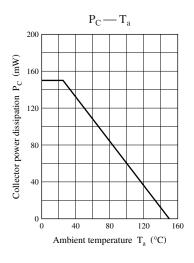
Parameter	Symbol	Conditions		Тур	Max	Unit
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 10 \text{ V}, I_{E} = 0$		250	1	μΑ
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 1 \text{ V}, I_C = 0$	- W		1	μΑ
Forward current transfer ratio *	h_{FE}	$V_{CE} = 8 \text{ V}, I_{C} = 20 \text{ mA}$	50		300	_
Transition frequency	f_T	$V_{CE} = 8 \text{ V}, I_{C} = 15 \text{ mA}, f = 1.5 \text{ GHz}$	7.0	8.5		GHz
Collector output capacitance	C _{ob}	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$		0.6	1.0	pF
(Common base, input open circuited)		7/10, 50,				
Forward transfer gain	S _{21e} 2	$V_{CE} = 8 \text{ V}, I_{C} = 15 \text{ mA}, f = 1.5 \text{ GHz}$	7	9		dB
Maximum unilateral power gain	G_{UM}	$V_{CE} = 8 \text{ V}, I_{C} = 15 \text{ mA}, f = 1.5 \text{ GHz}$		10		dB
Noise figure	NF	$V_{CE} = 8 \text{ V}, I_{C} = 7 \text{ mA}, f = 1.5 \text{ GHz}$		2.2	3.0	dB

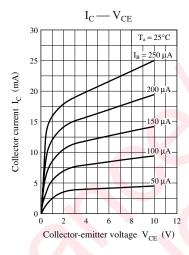
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

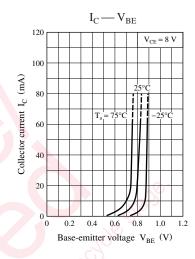
2. *: Rank classification

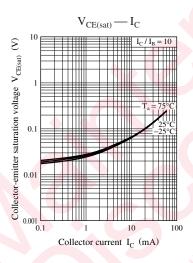
Rank	Q	R	S	No-rank
h_{FE}	50 to 120	100 to 170	150 to 300	50 to 300
Marking symbol	3SQ	3SR	3SS	3S

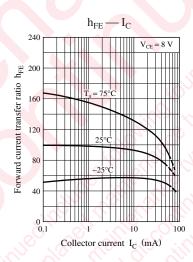
Product of no-rank is not classified and have no indication for rank.

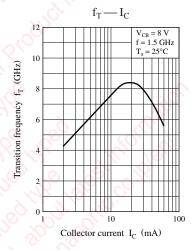


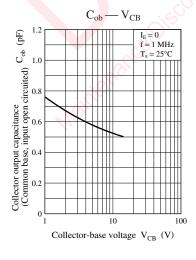


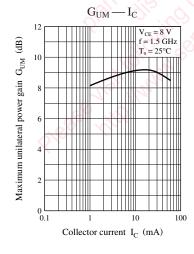


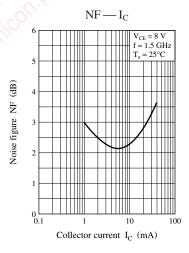




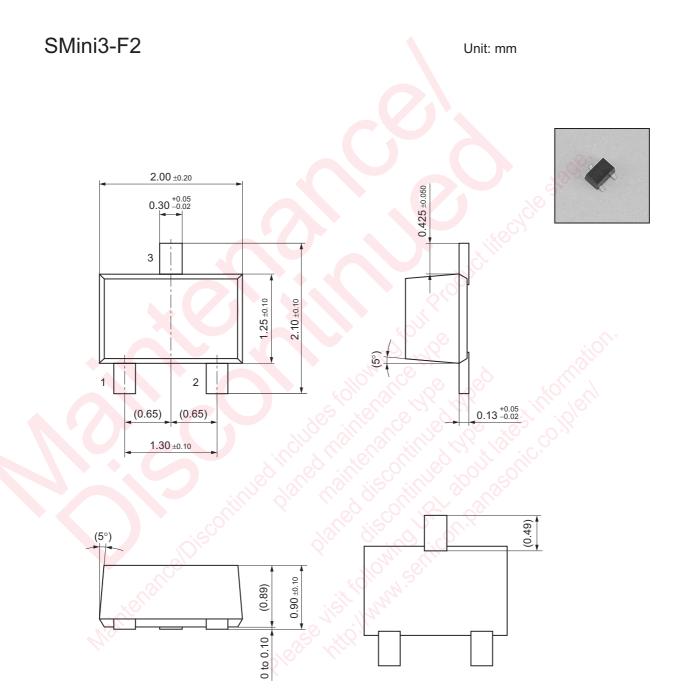








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